

SHD226309

TECHNICAL DATA DATA SHEET 619, REV -

HERMETIC POWER MOSFET P-CHANNEL

FEATURES:

- 100 Volt, 0.31 Ohm, -9.3 A MOSFET
- Fast Switching
- Low R_{DS (on)}
- Equivalent to IRFY9130 Series
- Add a "C" to the part number for ceramic seals, SHDC226309

MAXIMUM RATINGS

ALL RATINGS ARE AT T_c = 25°C UNLESS OTHERWISE SPECIFIED.

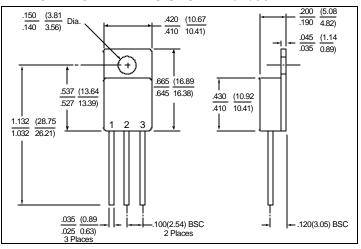
| RATING | SYMBOL | MIN. | TYP. | MAX. | UNITS |
|--|---------------------|------|------|------|-------|
| GATE TO SOURCE VOLTAGE | V _{GS} | - | - | ±20 | Volts |
| ON-STATE DRAIN CURRENT @ T _C = 25°C | I _{D (on)} | - | - | -9.3 | Amps |
| PULSED DRAIN CURRENT @ T _C = 25°C | I _{DM} | - | - | 5.8 | Amps |
| OPERATING AND STORAGE TEMPERATURE | T_{OP}/T_{STG} | -55 | - | +150 | °C |
| THERMAL RESISTANCE, JUNCTION TO CASE | R _{thJC} | - | - | 1.4 | °C/W |
| TOTAL DEVICE DISSIPATION @ T _C = 25°C | PD | - | - | 89 | Watts |

ELECTRICAL CHARACTERISTICS

| BV _{DSS} | -100 | - | - | Volts |
|---------------------|--|--|--|--|
| | | | | |
| Q _{gs} | 1.0 | - | 7.1 | nC |
| | | | | |
| Q _{gd} | 2.1 | - | 21 | nC |
| _ | | | | |
| | - | - | | |
| R _{DS(ON)} | | | 0.31 | Ω |
| | | | 0.36 | |
| V _{GS(th)} | -2.0 | - | -4.0 | Volts |
| g fs | 2.5 | - | - | S(1/Ω) |
| | | | | |
| | - | - | | |
| IDSS | | | -25 | μA |
| | | | -250 | • |
| I _{GSS} | - | - | 100 | nA |
| | | | -100 | |
| t _{d(ON)} | - | - | 60 | |
| tr | | | 140 | nsec |
| t _{d(OFF)} | | | 140 | |
| t _f | | | 140 | |
| V _{SD} | - | - | -4.7 | Volts |
| | | | | |
| t _{rr} | - | - | | |
| | | | 250 | nsec |
| | | | | |
| C _{iss} | - | 800 | - | |
| | | 350 | | pF |
| C _{rss} | | 125 | | • |
| | $\begin{array}{c} Q_{gs} \\ Q_{gd} \\ \hline \\ R_{DS(ON)} \\ \hline \\ V_{GS(th)} \\ g_{fs} \\ \hline \\ I_{DSS} \\ I_{GSS} \\ \hline \\ I_{d(ON)} \\ t_r \\ t_{d(OFF)} \\ t_f \\ \hline \\ V_{SD} \\ \hline \\ t_{rr} \\ \hline \\ C_{iss} \\ C_{oss} \\ \hline \end{array}$ | $\begin{array}{c c c c c c c c } Q_{gs} & 1.0 \\ \hline Q_{gd} & 2.1 \\ \hline R_{DS(ON)} & - \\ \hline & & - \\ \hline & & & - \\ \hline & & & & - \\ \hline & & & & & & \\ \hline & & & & & & \\ \hline & & & &$ | $\begin{array}{c c c c c c c c c c c c c c c c c c c $ | $\begin{array}{c c c c c c c c c c c c c c c c c c c $ |

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SENSITRON DATA SHEET 619 REVISION -



MECHANICAL DIMENSIONS: in Inches / mm

<u>TO-257</u>

PINOUT TABLE

| DEVICE TYPE | PIN 1 | PIN 2 | PIN 3 |
|----------------|-------|--------|-------|
| MOSFET | DRAIN | SOURCE | GATE |
| TO-257 PACKAGE | | | |



TECHNICAL DATA

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